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Silicon Power Transistors

The NJW21193G and NJW21194G utilize Perforated Emitter technology and are specifically designed for high power audio output, disk head positioners and linear applications.

Features

- Total Harmonic Distortion Characterized
- High DC Current Gain
- Excellent Gain Linearity
- High SOA
- These Devices are Pb-Free and are RoHS Compliant

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V _{CEO}	250	Vdc
Collector-Base Voltage	V _{CBO}	400	Vdc
Emitter-Base Voltage	V _{EBO}	5.0	Vdc
Collector-Emitter Voltage - 1.5 V	V _{CEX}	400	Vdc
Collector Current – Continuous	۱ _C	16	Adc
Collector Current – Peak (Note 1)	I _{CM}	30	Adc
Base Current – Continuous	Ι _Β	5.0	Adc
Total Power Dissipation @ T _C = 25°C Derate Above 25°C	P _D	200 1.6	W W/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	– 65 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability. 1. Pulse Test: Pulse Width = 5 μ s, Duty Cycle \leq 10%.

1. Therefore 1000 Therefore 1000 Therefore 1000 Therefore 1000

THERMAL CHARACTERISTICS

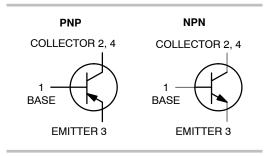
Characteristic	Symbol	Мах	Unit
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	0.625	°C/W
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	40	°C/W

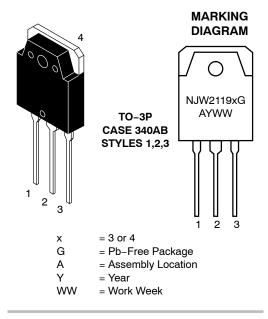


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16 AMPERES COMPLEMENTARY SILICON POWER TRANSISTORS 250 VOLTS, 200 WATTS





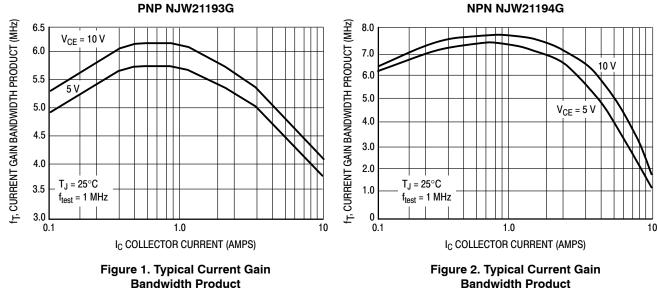
ORDERING INFORMATION

Device	Package	Shipping
NJW21193G	TO–3P (Pb–Free)	30 Units/Rail
NJW21194G	TO-3P (Pb-Free)	30 Units/Rail

Semiconductor Components Industries, LLC, 2013 September, 2013 – Rev. 1

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS					
Collector-Emitter Sustaining Voltage $(I_C = 100 \text{ mAdc}, I_B = 0)$	V _{CEO(sus)}	250	_	_	Vdc
Collector Cutoff Current ($V_{CE} = 200 \text{ Vdc}, I_B = 0$)	I _{CEO}	-	_	100	μAdc
Emitter Cutoff Current ($V_{CE} = 5 \text{ Vdc}, I_C = 0$)	I _{EBO}	-	_	100	μAdc
Collector Cutoff Current (V _{CE} = 250 Vdc, V _{BE(off)} = 1.5 Vdc)	ICEX	-	_	100	μAdc
SECOND BREAKDOWN				-	
Second Breakdown Collector Current with Base Forward Biase $(V_{CE} = 50 \text{ Vdc}, t = 1 \text{ s (non-repetitive)})$ $(V_{CE} = 80 \text{ Vdc}, t = 1 \text{ s (non-repetitive)})$	ed I _{S/b}	4.0 2.25			Adc
ON CHARACTERISTICS				-	
DC Current Gain (I _C = 8 Adc, V _{CE} = 5 Vdc) (I _C = 16 Adc, I _B = 5 Adc)	h _{FE}	20 8		80 -	
Base-Emitter On Voltage (I _C = 8 Adc, V _{CE} = 5 Vdc)	V _{BE(on)}	-	_	2.2	Vdc
Collector-Emitter Saturation Voltage ($I_C = 8 \text{ Adc}, I_B = 0.8 \text{ Adc}$) ($I_C = 16 \text{ Adc}, I_B = 3.2 \text{ Adc}$)	V _{CE(sat)}	-	-	1.4 4	Vdc
DYNAMIC CHARACTERISTICS					
Total Harmonic Distortion at the Output V _{RMS} = 28.3 V, f = 1 kHz, P _{LOAD} = 100 W _{RMS} h _{FE} unmatch	T _{HD}	_	0.8	_	%
(Matched pair h_{FE} = 50 @ 5 A/5 V) h_{FE} matched		_	0.08	-	
Current Gain Bandwidth Product $(I_C = 1 \text{ Adc}, V_{CE} = 10 \text{ Vdc}, f_{test} = 1 \text{ MHz})$	f _T	4	-	-	MHz
Output Capacitance (V _{CB} = 10 Vdc, I _E = 0, f _{test} = 1 MHz)	C _{ob}	-	-	500	pF





TYPICAL CHARACTERISTICS

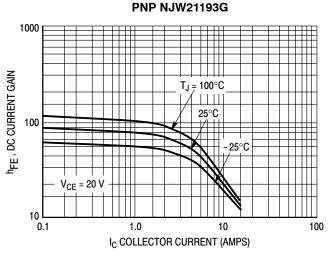
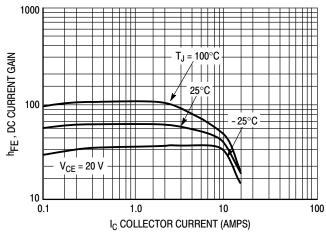


Figure 3. DC Current Gain, V_{CE} = 20 V



NPN NJW21194G

Figure 4. DC Current Gain, V_{CE} = 20 V

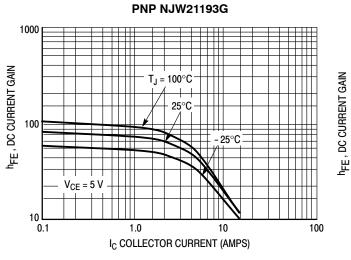
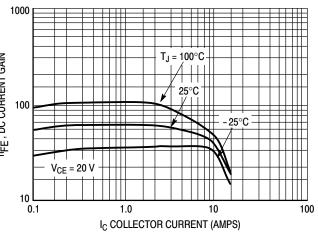
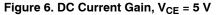


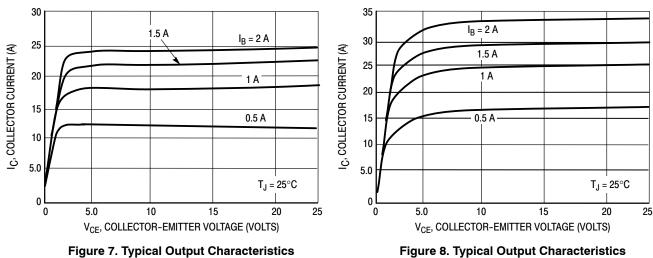
Figure 5. DC Current Gain, $V_{CE} = 5 V$







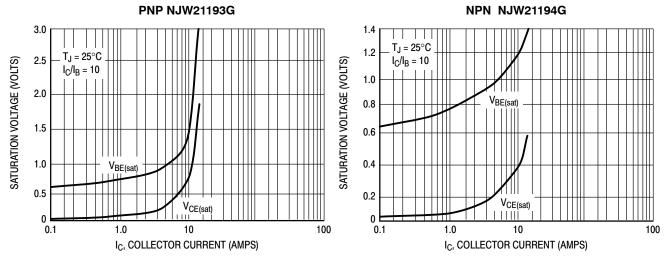
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PNP NJW21193G

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TYPICAL CHARACTERISTICS







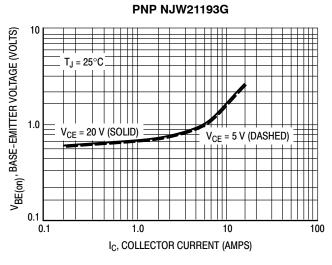


Figure 11. Typical Base-Emitter Voltage

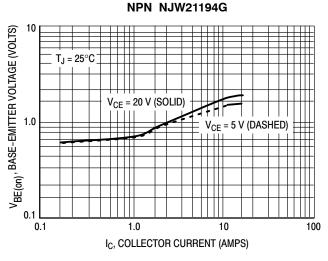


Figure 12. Typical Base-Emitter Voltage

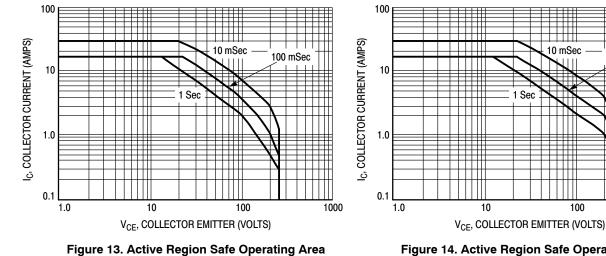
NPN NJW21194G

10 mSec

100

100 mSec

1000



PNP NJW21193G



There are two limitations on the power handling ability of a transistor; average junction temperature and secondary breakdown. Safe operating area curves indicate $I_C - V_{CE}$ limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 13 is based on $T_{J(pk)} = 150^{\circ}$ C; T_{C} is variable depending on conditions. At high case temperatures, thermal limitations will reduce the power than can be handled to values less than the limitations imposed by second breakdown.

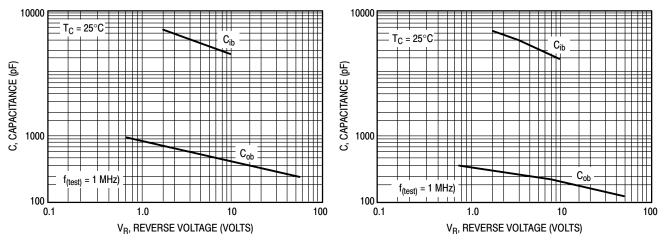


Figure 15. NJW21193G Typical Capacitance

Figure 16. NJW21194G Typical Capacitance

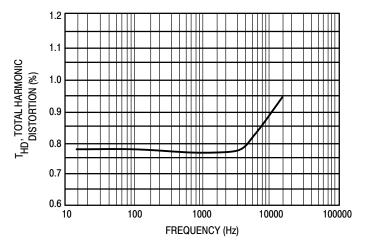


Figure 17. Typical Total Harmonic Distortion

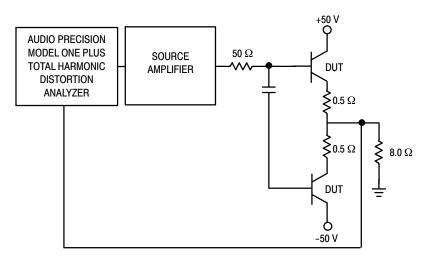
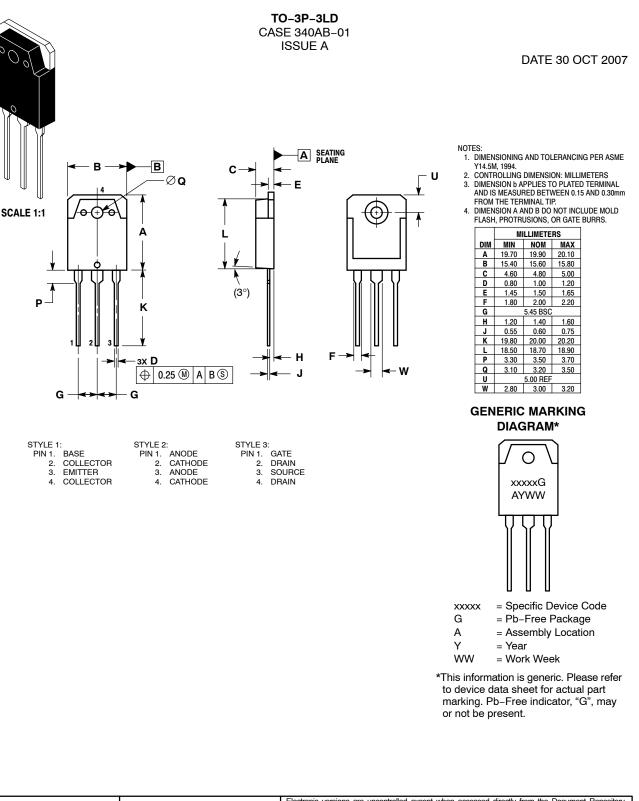


Figure 18. Total Harmonic Distortion Test Circuit

MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS





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